Perpendicular giant magnetoresistance of Co/Cu multilayers on grooved substrates: systematic analysis of the temperature dependence of spin-dependent scattering


DOI: 10.1103/PhysRevB.53.14024

Document status and date:
Published: 01/01/1996

Document Version:
Publisher’s PDF, also known as Version of Record (includes final page, issue and volume numbers)

Please check the document version of this publication:

• A submitted manuscript is the version of the article upon submission and before peer-review. There can be important differences between the submitted version and the official published version of record. People interested in the research are advised to contact the author for the final version of the publication, or visit the DOI to the publisher’s website.
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Download date: 23. Apr. 2019
Perpendicular giant magnetoresistance of Co/Cu multilayers on grooved substrates: Systematic analysis of the temperature dependence of spin-dependent scattering

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(Received 28 November 1995; revised manuscript received 12 February 1996)

The giant magnetoresistance of Co/Cu multilayers deposited at an angle onto grooved substrates is measured with the current perpendicular to the layer plane. The spin-dependent scattering parameters due to magnetic bulk and interface scattering are determined as a function of temperature, which is done by comparing our experiments with the two-channel model. We find that the decrease of the magnetoresistance from 4.2 K to room temperature is mainly due to an increase of the bulk resistivities of the Co and Cu layers, while the temperature dependence of the interface resistance and the spin-asymmetry parameters for electron scattering is small. [S0163-1829(96)03622-3]

The discovery of the giant magnetoresistance (MR) effect in magnetic multilayers, has led to numerous experimental studies on this effect by many groups. Different multilayer systems as well as different experimental geometries have been investigated. Transport experiments in magnetic multilayers can be divided in two types: (i) The current flows in the plane of the layers (CIP) and (ii) the current is directed perpendicularly to the layer plane (CPP). A description of the giant magnetoresistance effect is theoretically more complex in the CIP geometry than in the CPP geometry. However, experimentally the CPP MR is much harder to access than the CIP MR due to the low perpendicular resistances involved. Several methods have been developed to measure the magnetoresistance of a multilayer in the CPP geometry. The first CPP MR measurements have been done by using superconducting contacting-quantum-interference-device (SQUID-) based voltage measuring techniques at low temperatures. Subsequently also microfabricated, so-called “pillar,” structures have been employed. This method allows one the investigation of the temperature dependence of the CPP MR effect. Unfortunately, this fabrication method is rather complicated and the contact resistance to the pillars is often a problem. A third technique is the electrolytic growth of multilayers into nanopores made into insulating membranes resulting in columns with a large aspect ratio and resistances in a convenient range. Recently, we introduced an alternative and simple technique for measuring CPP MR, based on the oblique evaporation of multilayers on to grooved substrates. At the same time also perpendicular growth of thick multilayers on grooved substrates was investigated. From measurements with currents at different angles to the grooves [the so-called current at an angle to layer plane (CAP) geometry], it has been possible to derive the CPP MR of the multilayer.

In this paper we report on temperature-dependent CPP MR experiments on Co/Cu multilayers fabricated with the oblique evaporation technique. We have chosen for the Co/Cu multilayer system since this is by now a well-known system, making comparison with the literature possible. It is emphasized, however, that this technique can also be applied to other systems. We compare the experimental data with the phenomenological two-channel model introduced by Lee et al. We systematically analyze the relevant spin-dependent scattering parameters as a function of temperature; this has previously not been possible with the other techniques. We find that the Co/Cu interface resistance keeps its strong spin dependence at all temperatures. The main reason for the decrease of the MR with temperature is the increasing importance of bulk scattering with intrinsically much smaller spin dependence. We compare our low-temperature data with CPP MR experiments on Co/Cu done at Michigan State University, and find that these are similar.

The V-groove pattern in the semi-insulating InP substrates is fabricated using holographic laser interference lithography and anisotropic etching techniques. Details of this fabrication process have been recently described elsewhere. The grooves are formed by (111) planes which have an 54.7° angle to each other and have a period of typically 200 nm. The multilayer stacks are grown in a multichamber molecular beam epitaxy (MBE) system (VG Semicon V80M). The deposition takes place at room temperature, at a pressure better than 10^{-10} mbar. By evaporating at an angle perpendicular to one series of (111) planes, we naturally grow stacks of multilayers on one side of the grooves. When the individual stacks overlap, contact is made between the top and the bottom of neighboring stacks, which leads to a series connection of the stacks. A sample consists of typically 5000 to 10 000 stacks in series. To optimize a perpendicular current distribution, we start and end the growth with...
We have tried to demagnetize the samples by spinning them in a magnetic field (of approximately 0.3 T). This enhanced the CPP MR value, but the \( R(H_0) \) state could not be recovered completely. The \( R(H_{\text{max}}) \) value after magnetic field cycling always returned to the same value, which shows that this state is very well reproducible. The initial CPP MR of the sample shown in Fig. 1 is 12.2% at room temperature and 35.0% at 4.2 K. The initial CPP MR value at room temperature is 4.3%.

We compared our CPP MR data to the so-called “two-channel” model, first used by Lee et al.\(^7\) and microscopically justified by Camblong et al.\(^10\) and by Valet and Fert.\(^11\) In this model, the resistivity of the ferromagnetic layers in the configuration where the electron spin and the local magnetization are parallel (antiparallel) to each other is defined as \( \rho_F = 2\rho_F/(1 + \beta) \) \( \rho_F = 2\rho_F/(1 - \beta) \). Here, \( \rho_F \) is the bulk resistivity of Co. Similarly, also for the ferromagnet/normal metal interface, spin-dependent resistances can be defined: \( R_{\text{FIN}} = 2R_{\text{F/N}}/(1 + \gamma) \) and \( R_{\text{FIN}} = 2R_{\text{F/N}}/(1 - \gamma) \). \( \beta \) and \( \gamma \) are the important spin-asymmetry parameters of the bulk and the interface, respectively. When identifying the resistance at \( H_H \) with a situation of antiparallel alignment of magnetizations, one obtains for the total perpendicular resistance per unit surface \( AR_T \)

\[
AR_T(H_0) = M[\rho_N t_N + \rho_F t_F + 2AR_{\text{FIN}}^p],
\]

with \( \rho_N = \rho_F/(1 - \beta^2), R_{\text{FIN}}^p = R_{\text{F/N}}^p/(1 - \gamma^2) \), \( M \) the number of bilayers, and \( A \) the perpendicular cross section of one multilayer stack. In our analysis we transform our measured resistance to a resistance per stack. Another useful relation for comparison to the experiment\(^7\) is given by

\[
A\sqrt{R_T(H_0) - R_T(H_{\text{sat}})} = M[\beta\rho_F t_F + 2\gamma AR_{\text{FIN}}^p].
\]

It has been shown\(^7\) that the unknown scattering parameters of the model can be obtained from resistance measurements on a series of samples with constant total thickness \( L \) and with a varying thickness \( t_F \) or \( t_N \). By plotting the two data series according to Eqs. (1) and (2), we obtained for both equations a linear dependence on \( M \). The values of the slopes and intercepts of the ordinate axes of these plots were then used to determine the relevant parameters of the model. The errors of these parameters are derived from the errors in the determination of the slopes and intercepts in the plots. This is done for several temperatures between 4.2 K and room temperature. This simple two-channel model has been used for analyzing our experimental data at all temperatures. In a more complex temperature-dependent model, the most important addition is a spin-mixing contribution reducing the CPP MR.\(^12\) This spin-mixing term is determined by temperature-dependent coherent spin-flip scattering. From earlier CPP measurements on Co/Cu pillar structures this spin-flip scattering was found to be rather small up to room temperature.\(^13\) Therefore, in a first-order approximation, we neglect the influence of the spin-mixing term, and apply Eqs. (1) and (2) up to room temperature.

Results of our systematic analysis are plotted in Figs. 2 and 3. In Fig. 2 the interface scattering parameters are plotted. The spin-asymmetry parameter \( \gamma \) is first plotted as derived from both the \( R(H_0) \) and \( R(H_{\text{max}}) \) data. A weak de-
The temperature dependence of the spin-asymmetry parameter is shown. The Co/Cu interface resistance is plotted for both spin channels in the bottom part of Fig. 2. The interface resistance is within the accuracy of our data, independent of temperature, and also the asymmetry between $\rho_{\text{Co/Cu}}^{\uparrow}$ and $\rho_{\text{Co/Cu}}^{\downarrow}$ has a negligible temperature dependence. In Fig. 3 we plot the model fitting parameters for the bulk resistivities. The spin-asymmetry parameter $\beta$ is found to be lower than the spin-asymmetry parameter $\gamma$ and is temperature independent. The resistivities for both spin channels in the Co layers and the resistivity of the Cu layer are given in the bottom part of Fig. 3. Both resistivities increase linearly with temperature. The resistivity of the Cu layer is very low; it is obvious that the contribution of the Cu layer in the total resistance is very weak. The room temperature resistivity of the Cu layer is 1.56 $\mu\Omega$ cm, which is similar to the bulk resistivity of MBE-grown Cu films. The room temperature resistivity of the Co layer is 11.5 $\mu\Omega$ cm. The difference in the up- and down-spin channel resistivities of Co is increasing weakly as a function of temperature. Our analysis demonstrates that the main reason for the decrease of the MR value at higher temperatures is the increase of the bulk resistivities, which have a smaller (Co) and zero (Cu) spin asymmetry with respect to the interface. The weak temperature dependence of the spin-asymmetry parameters $\beta$ and $\gamma$ suggests that our assumption of a low spin mixing at higher temperatures indeed is correct, which seems to justify the use of the two-channel model. In Table I we give our spin-dependent parameters at 4.2 K and compare them to the Co/Cu results of the superconducting contact experiments done at the Michigan State University$^{8,14}$ and the electrolytically grown wires by Piraux et al.$^{15}$ The value we find for the interface resistance $\rho_{\text{Co/Cu}}$ is quite similar to the value found with the superconducting contact technique. The values of $\beta$ and $\gamma$ in our work are lower than the values found in the other experiments. Besides the fact that our multilayers have been MBE grown, which might introduce a difference, this is due to the fact that our measuring configuration is not purely CPP at the extreme ends of the multilayer stack. An uncertainty in our analysis is the exact length of the part in the grown multilayer where the current is really flowing perpendicular to the layer planes. When we assume a shorter length, and an extra contact resistance between the stacks, we find higher values for $\beta$ and the resistivities. We have estimated, using finite element calculations, that the resistance contribution of the current flowing perpendicular to the layers is more than 75% of the total resistance. Compared with the MR values with the superconducting contact technique we find that our MR values of comparable multilayers are approximately 20% lower, which is in agreement with our calculations. Although we find a somewhat reduced MR, we want to stress that choosing for this technique pays off well: We can reproducibly fabricate samples with many thousands of “pillars” in series, enabling a systematic study of all spin-dependent scattering parameters of the multilayer as a function of temperature.
TABLE I. Overview of the spin-dependent scattering parameters at low temperatures as derived from our measurements, compared with the superconducting contact technique (Refs. 8,14), and with the electrodeposition technique (Ref. 15). The parameters are defined and discussed in the text.

<table>
<thead>
<tr>
<th>Method</th>
<th>$AR_{FN}$ $[\Omega \cdot m^2]$</th>
<th>$\beta$</th>
<th>$\gamma$</th>
<th>$\rho_{Co} [\mu\Omega \cdot cm]$</th>
<th>$\rho_{Cu} [\mu\Omega \cdot cm]$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Grooved substrates $H_0$ data 4.2 K</td>
<td>0.20$\pm$0.04</td>
<td>0.27$\pm$0.05</td>
<td>0.52$\pm$0.10</td>
<td>5.3$\pm$0.6</td>
<td>0.36$\pm$0.06</td>
</tr>
<tr>
<td>Grooved substrates $H_{max}$ data 4.2 K</td>
<td>0.20$\pm$0.04</td>
<td>0.17$\pm$0.03</td>
<td>0.45$\pm$0.09</td>
<td>4.1$\pm$0.7</td>
<td>0.39$\pm$0.07</td>
</tr>
<tr>
<td>Superconducting contacts $H_0$ data 4.2 K&lt;sup&gt;a&lt;/sup&gt;</td>
<td>0.21$\pm$0.01</td>
<td>0.50$\pm$0.10</td>
<td>0.76$\pm$0.05</td>
<td>6.45$\pm$0.34</td>
<td>0.67$\pm$0.20</td>
</tr>
<tr>
<td>Superconducting contacts $H_{max}$ data 4.2 K&lt;sup&gt;b&lt;/sup&gt;</td>
<td>0.19$\pm$0.02</td>
<td>0.38$\pm$0.06</td>
<td>0.71$\pm$0.05</td>
<td>5.66$\pm$0.12</td>
<td>1.2$\pm$0.31</td>
</tr>
<tr>
<td>Electrodeposited nanowires $H_{max}$ data 77 K&lt;sup&gt;c&lt;/sup&gt;</td>
<td>0.08$\pm$0.05</td>
<td>0.36$\pm$0.04</td>
<td>0.85$\pm$0.1</td>
<td>20$\pm$2</td>
<td>3.1</td>
</tr>
</tbody>
</table>

<sup>a</sup>Reference 8.
<sup>b</sup>Reference 14.
<sup>c</sup>Reference 15.

In summary, we have discussed an analysis of the perpendicular CPP magnetoresistance in magnetic multilayers. Co/Cu multilayers are evaporated at an angle onto grooved substrates fabricated by holographic laser interference lithography and anisotropic etching, naturally giving rise to a CPP-like measuring geometry. Using this method we have determined systematically as a function of temperature all the important scattering parameters, by comparing our experimental data with a theoretical model. We have found that the spin-dependent scattering parameters vary weakly with temperature. An important result of our analysis is that the Co/Cu interface resistance keeps its strong spin dependence at all temperatures. The main reason for the decrease of the MR with temperature is the increasing importance of bulk scattering with an intrinsically much smaller spin dependence. We have compared our low-temperature data with values found in multilayers grown by other techniques, and have found that our spin-asymmetry parameters are in the line of values found by other authors.

The authors would like to thank R. P. Tijburg, P. E. Huisman, and J. G. H. Stiepen for the fabrication of the grooved substrates and S. K. J. Lenczowski, R. J. M. van de Veerdonk, K. M. Schep, and H. van Houten for useful discussions.

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14. J. Bass (private communication).